

**2,84** μ**m** 



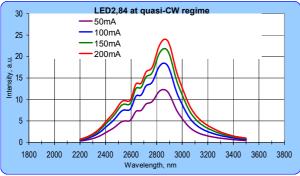
Light Emitting Diodes with central wavelength 2,84  $\mu m$  series are based on heterostructures grown on InAs substrates. InAsSbP is used in the active layer. Wide band gap solid solutions InAsSbP with P content 50% are used for good electron confinement.

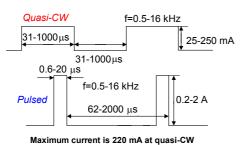
Parameters	Units Conditions	Ratings			
		Conditions	Min	Тур	Max
Peak emission wavelength	μm	T=300 K	2,80	2,84	2,90
FWHM of the emission band	nm	150 mA CW	300	400	500
Quasi-CW Optical Power	μW	200 mA qCW	18	25	35
Pulsed Optical Power	μW	1 A	120	150	170
Switching Time	ns	T=300 K	10	20	30
Operating Temperature Range, °C	-240° ÷ +50°				
Emitting Area, μm	300x300				
Soldering temperature	260 °C				
Package					
TO-18 with a non-removable cap without a window			MID IR LED		
TO-18 with a parabolic reflector without a window			MID IR LED-PR		
TO-18 with a parabolic reflector with a window			MID IR LED-PRwin		
TO-5 with a built-in thermocooler and thermoresistor, covered by a cap with a window			MID IR LED-TEC		
TO-5 with a built-in thermocooler and thermoresistor, covered by a parabolic reflector with a window			MID IR LED-TEC-PR		

Spectra at different temperatures I=150 mA

2800

3000





Maximum pulsed current is 1 A (duration 500 ns, repetition rate 2 kHz) Optimal operating current is 150-200 mA at quasi-CW.

240

200

160

120

80

40

-40

٩

Current.

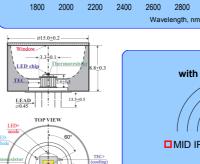
-500

LED2,84 Typical Current-Voltage characteristic

500

Voltage, mV

1000



. ∅ 5.0+0.

30,0

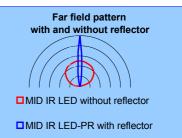
25,0

20,0 л.

5.0

0.0

sity, 15,0 Inte 10,0

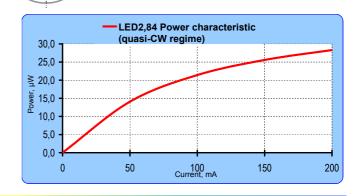


3200

3400

3600

3800



## **RELATED PRODUCTS**

1500

LED driver with temperature controller DLT-37 can be used for LED power supply in quasi-CW and pulse modes LED driver with temperature controller DLT-27 can be used for LED power supply in quasi-CW and pulse modes at fixed frequency and pulse duration

## PD36 series Photodiodes can be used for detecting LED emission